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### Dielectric Measurements Using a Reentrant Cavity: Mode-Matching Analysis

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#### Abstract

The coaxial reentrant cavity dielectric measurement technique is examined. A full-mode model for the cavity is developed and solved numerically. Analytical expressions for wall losses are presented. The filling factor due to a partially-filled cavity is discussed. Dielectric results are presented and compare very closely to previous round-robin results.

Key words: cavity; coaxial; dielectric constant; loss factor; microwave measurements; permeability measurement; permittivity measurement; reentrant; resonant

#### 1. Introduction

In this report we develop the theory underlying the reentrant-cavity dielectric measurement technique. A full-mode model for the cavity is developed and solved numerically. Analytical expressions for reentrant-cavity characterization are presented.

Many radio-frequency applications require an accurate value of the component of the permittivity normal to the plane of the material. The reentrant cavity is unique since it is possible to accurately measure materials at frequencies from 100 MHz to 1 GHz with axial electric field [1, 2]. The reentrant cavity consists of a coaxial line or other transmission line with end walls, and a gap in the inner electrode where a sample is positioned. If the gap is at either end of the cavity, then the system is a singly reentrant cavity; otherwise it is a doubly reentrant cavity. The doubly reentrant cavity has a stronger electric field in the gap than the singly reentrant cavity and

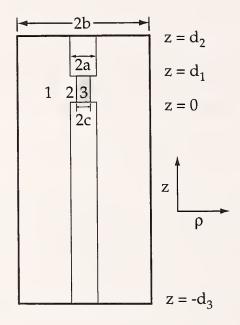


Figure 1: The reentrant cavity with regions 1, 2, and 3 denoted. The coaxial line inner and outer diameters 2a and 2b, and sample diameter 2c are indicated in the figure.

is more useful for permittivity determination. Applications include measurements of substrates, circuit boards, printed-wiring boards, and bulk materials.

Two approaches have been used for modeling the reentrant cavity. The first is a lumped-circuit approximation [1, 2]. The other approach, which we develop in detail, is a rigorous mode-matching technique [3-5]. Our approach differs from previous work in that we develop the full mode-matched solution for the doubly reentrant cavity and present the details of the calculations.

#### 2. Mode-Matching Theory

The reentrant cavity method can be used to measure either permittivity or permeability. Permeability is most accurately measured by placing the sample in the strong magnetic field near an end plate. Permittivity is most accurately measured in a region of strong electric field, such as in a gap in the center conductor away from the end plates. We will restrict our analysis to permittivity determination; however, the equations are valid for arbitrary permeability. The material under test is assumed to have permittivity of  $\epsilon_s^* = [\epsilon_r' - j\epsilon_r'']\epsilon_o = \epsilon_r^*\epsilon_o$  and permeability  $\mu_s^* = [\mu_r' - j\mu_r'']\mu_o = \mu_r^*\mu_o$ , where  $\epsilon_o$  and  $\mu_o$  are the permittivity and permeability of vacuum. The

dimensions of the cavity are shown in figure 1. The coaxial sections have inner and outer radii a and b, respectively. The sample has radius c, which may be smaller than the inner conductor radius. The sample thickness is  $d_1$ . In the mode-matching technique the frequency

$$\omega = \omega_r + j\omega_r/2Q,\tag{1}$$

where  $\omega_r$  is the measured resonant frequency and Q is the quality factor is complex.

We assume that only  $TM_{0m}$  modes are excited in the cavity. The TEM mode is excluded because of the gap in the center conductor. The fields can be derived from either  $H_{\phi}$  or  $E_z$  in all regions. The magnetic field satisfies the vector Helmholtz equation

$$\nabla^2 \vec{H} + k^2 \vec{H} = 0. \tag{2}$$

Symmetry requires that only an azimuthal magnetic field is excited.  $H_{\phi}$  satisfies

$$\left[\frac{\partial^2}{\partial \rho^2} + \frac{1}{\rho} \frac{\partial}{\partial \rho} - \frac{1}{\rho^2} + \frac{\partial^2}{\partial z^2} + k_i^2\right] H_{\phi(i)}(\rho, z) = 0 \tag{3}$$

in regions where i=1,2, or 3,  $k_i^2=\omega^2\epsilon_{ri}^*\mu_{ri}^*/c_v^2$ , and  $c_v$  is the speed of light relative to vacuum. The electric field components are  $E_z$  and  $E_\rho$ .

The boundary conditions on the fields are

$$E_{z}(a,z) = 0, \quad (d_{2} > z > d_{1}, \quad 0 > z > -d_{3}),$$

$$E_{z}(b,z) = 0, \quad (d_{2} > z > -d_{3}),$$

$$E_{\rho}(\rho, d_{2}) = E_{\rho}(\rho, -d_{3}) = 0, \quad (a < \rho < b),$$

$$E_{\rho}(\rho, d_{1}) = E_{\rho}(\rho, 0) = 0, \quad (0 < \rho < a),$$

$$E_{z}(a^{(+)}, z) = E_{z}(a^{(-)}, z), \quad (0 < z < d_{1}),$$

$$H_{\phi}(c^{(+)}, z) = H_{\phi}(c^{(-)}, z), \quad (0 < z < d_{1}),$$

$$H_{\phi}(a^{(+)}, z) = H_{\phi}(a^{(-)}, z), \quad (0 < z < d_{1}),$$

$$E_{z}(c^{(+)}, z) = E_{z}(c^{(-)}, z), \quad (0 < z < d_{1}).$$

$$(4)$$

The boundary-value problem defined in eqs (3) and (4) can be shown to be unique.

#### 2.1. Fields

In this section we develop expressions for  $TM_{0n}$  field structure in the reentrant cavity. The electric field has components  $E_{\rho}$  and  $E_z$ , and the magnetic field has component  $H_{\phi}$ . The general solution can be written in the form

$$H_{\phi(i)}(\rho, z) = \sum_{n} A_{n(i)} R_{n(i)}(\rho) f_{n(i)}(z).$$
 (5)

The eigenfunctions satisfy

$$\frac{d^2 f_n(z)}{dz^2} = -\lambda_n^2 f_n(z). \tag{6}$$

Since we require  $E_{\rho}$  to vanish at  $z=-d_3$  and  $z=d_2$  we must have

$$\frac{df_n}{dz}(z=d_2) = \frac{df_n}{dz}(z=-d_3) = 0; (7)$$

therefore in region 1

$$f_{n(1)}(z) = \cos((d_2 - z)n\pi/L),$$
 (8)

where  $L = d_2 + d_3$  and n = 0, 1, 2... In regions 2 and 3, the eigenfunctions satisfy eq (6) with the same boundary conditions, but on the ends of the inner conductor instead of on the cavity endplates. In regions 2 and 3,

$$f_{n(2)}(z) = \cos(n\pi z/d_1).$$
 (9)

The magnetic field in region 1 is

$$H_{\phi(1)}(\rho,z) = -\sum_{m=0}^{\infty} A_{m(1)} \frac{j\omega\epsilon_1^*}{\sqrt{k_1^2 - (m\pi/L)^2}} [J_1(\sqrt{k_1^2 - (m\pi/L)^2}\rho) + Q_{1m}N_1(\sqrt{k_1^2 - (m\pi/L)^2}\rho)] \times \cos((d_2 - z)m\pi/L).$$
(10)

 $J_1$ ,  $N_1$ ,  $J_0$ , and  $N_0$  are Bessel functions of complex argument. Equation (10) is written in a form to be consistent with previous publications [3]. The other field components can be generated by

$$E_{\rho} = -\frac{1}{j\omega\epsilon^*} \frac{\partial H_{\phi}}{\partial z},\tag{11}$$

$$E_z = \frac{1}{j\omega\epsilon^*} \frac{1}{\rho} \frac{\partial(\rho H_\phi)}{\partial \rho}.$$
 (12)

These are

$$E_{\rho(1)}(\rho, z) = \sum_{m=1}^{\infty} A_{m(1)} \frac{(m\pi/L)}{\sqrt{k_1^2 - (m\pi/L)^2}} [J_1(\sqrt{k_1^2 - (m\pi/L)^2}\rho) + Q_{1m}N_1(\sqrt{k_1^2 - (m\pi/L)^2}\rho)] \times \sin((d_2 - z)m\pi/L),$$
(13)

$$E_{z(1)}(\rho, z) = -\sum_{m=0}^{\infty} A_{m(1)} [J_0(\sqrt{k_1^2 - (m\pi/L)^2}\rho) + Q_{1m} N_0(\sqrt{k_1^2 - (m\pi/L)^2}\rho)] \times \cos(m\pi(d_2 - z)/L).$$
(14)

The condition that  $E_{\rho}$  vanishes on the outer conductor requires

$$Q_{1m} = -\frac{J_0(\sqrt{k_1^2 - (m\pi/L)^2 b})}{N_0(\sqrt{k_1^2 - (m\pi/L)^2 b})}.$$
(15)

In region 2, the fields are

$$E_{z(2)}(\rho, z) = -\sum_{m=0}^{\infty} A_{m(2)} [J_0(\sqrt{k_2^2 - (m\pi/d_1)^2}\rho) + Q_{2m} N_0(\sqrt{k_2^2 - (m\pi/d_1)^2}\rho)] \cos(m\pi z/d_1),$$
(16)

$$E_{\rho(2)}(\rho, z) = \sum_{m=1}^{\infty} A_{m(2)} \frac{(m\pi/d_1)}{\sqrt{k_2^2 - (m\pi/d_1)^2}} [J_1(\sqrt{k_2^2 - (m\pi/d_1)^2}\rho) + Q_{2m} N_1(\sqrt{k_2^2 - (m\pi/d_1)^2}\rho)] \sin(m\pi z/d_1),$$
(17)

$$H_{\phi(2)}(\rho,z) = -\sum_{m=0}^{\infty} A_{m(2)} \frac{j\omega\epsilon_2^*}{\sqrt{k_2^2 - (m\pi/d_1)^2}} [J_1(\sqrt{k_2^2 - (m\pi/d_1)^2}\rho) + Q_{2m}N_1(\sqrt{k_2^2 - (m\pi/d_1)^2}\rho)] \cos(m\pi z/d_1).$$
(18)

In region 3, where the sample resides, the fields are

$$E_{z(3)}(\rho, z) = -\sum_{m=0}^{\infty} A_{m(3)} J_0(\sqrt{k_3^2 - (m\pi/d_1)^2} \rho) \cos(m\pi z/d_1),$$
 (19)

$$E_{\rho(3)}(\rho,z) = \sum_{m=1}^{\infty} A_{m(3)} \frac{(m\pi/d_1)}{\sqrt{k_3^2 - (m\pi/d_1)^2}} J_1(\sqrt{k_3^2 - (m\pi/d_1)^2}\rho) \sin(m\pi z/d_1), \tag{20}$$

$$H_{\phi(3)}(\rho, z) = -\sum_{m=0}^{\infty} A_{m(3)} \frac{j\omega\epsilon_3^*}{\sqrt{k_3^2 - (m\pi/d_1)^2}} J_1(\sqrt{k_3^2 - (m\pi/d_1)^2}\rho) \cos(m\pi z/d_1).$$
 (21)

#### 2.2. Matching between Regions

If we equate expansions for  $H_{\phi}$  between regions 1 and 2, at  $\rho = a$  in eqs (10) and (18), multiply each side by an axial eigenfunction, and integrate over  $[0, d_1]$ , we obtain the following system of equations

$$\frac{d_1}{2}(1+\delta_{n0})A_{n(2)}\frac{\epsilon_2^*}{\sqrt{k_2^2-(n\pi/d_1)^2}}[J_1(\sqrt{k_2^2-(n\pi/d_1)^2}a)+Q_{2n}N_1(\sqrt{k_2^2-(n\pi/d_1)^2}a)]$$
(22)

$$= \sum_{m=0}^{\infty} A_{m(1)} B_{mn} \frac{\epsilon_1^*}{\sqrt{k_1^2 - (m\pi/L)^2}} [J_1(\sqrt{k_1^2 - (m\pi/L)^2}a) + Q_{1m} N_1(\sqrt{k_1^2 - (m\pi/L)^2}a)].$$
 (23)

Equation 23 may be rearranged and expressed in vector form

$$\vec{A}_2 = \mathbf{L_5} \vec{A}_1,\tag{24}$$

where

$$L_{5mn} = \frac{B_{mn} \frac{\epsilon_1^*}{\sqrt{k_1^2 - (m\pi/L)^2}} [J_1(\sqrt{k_1^2 - (m\pi/L)^2}a) + Q_{1m}N_1(\sqrt{k_1^2 - (m\pi/L)^2}a)]}{\frac{d_1}{2} (1 + \delta_{n0}) \frac{\epsilon_2^*}{\sqrt{k_2^2 - (n\pi/d_1)^2}} [J_1(\sqrt{k_2^2 - (n\pi/d_1)^2}a) + Q_{2n}N_1(\sqrt{k_2^2 - (n\pi/d_1)^2}a)]}.$$
 (25)

Similarly, if we equate eqs (14) and (16) between regions 1 and 2, multiply each side by an axial eigenfunction, and integrate over  $[-d_3, d_2]$ , we obtain

$$\frac{L}{2}(1+\delta_{n0})A_{n(1)}[J_0(\sqrt{k_1^2-(n\pi/L)^2}a)+Q_{1n}N_0(\sqrt{k_1^2-(n\pi/L)^2}a)]$$

$$=\sum_{m=0}^{\infty}A_{m(2)}B_{mn}[J_0(\sqrt{k_2^2-(m\pi/d_1)^2}a)+Q_{2m}N_0(\sqrt{k_2^2-(m\pi/d_1)^2}a)], \tag{26}$$

or

$$\vec{A}_1 = \mathbf{L}_6 \vec{A}_2,\tag{27}$$

where

$$L_{6mn} = \frac{B_{mn} \left[ J_0(\sqrt{k_2^2 - (m\pi/d_1)^2} a) + Q_{2m} N_0(\sqrt{k_2^2 - (m\pi/d_1)^2} a) \right]}{\frac{L}{2} (1 + \delta_{n0}) \left[ J_0(\sqrt{k_1^2 - (n\pi/L)^2} a) + Q_{1n} N_0(\sqrt{k_1^2 - (n\pi/L)^2} a) \right]}.$$
 (28)

Requiring this integration to be 0 over  $d_1 < z < d_2$  and  $-d_3 < z < 0$  incorporates the boundary condition  $E_z = 0$  on the inner conductor.

The coefficients  $B_{mn}$  can be calculated analytically. For n = m,  $B_{mn} = d_1$ , otherwise

$$B_{mn} = \int_{0}^{d_{1}} \cos(n\pi z/d_{1}) \cos(m\pi (d_{2} - z)/L) dz$$

$$= \frac{d_{1}L \sin(\pi (\frac{d_{1}m}{L} - \frac{d_{2}m}{L} + n))}{2\pi (d_{1}m + Ln)} + \frac{d_{1}L \sin(\pi (\frac{d_{1}m}{L} - \frac{d_{2}m}{L} - n))}{2\pi (d_{1}m - Ln)}$$

$$+ \frac{d_{1}^{2}Lm}{\pi (d_{1}m - Ln)(d_{1}m + Ln)} \sin(\pi d_{2}m/L). \tag{29}$$

Since the modal fields decouple between regions 2 and 3 at  $\rho = c$ , we can write

$$A_{m(2)}[J_0(\sqrt{k_2^2 - (m\pi/d_1)^2}c) + Q_{2m}N_0(\sqrt{k_2^2 - (m\pi/d_1)^2}c)] = A_{m(3)}J_0(\sqrt{k_3^2 - (m\pi/d_1)^2}c), \quad (30)$$

and therefore,

$$A_{m(3)} \frac{\epsilon_3^* \sqrt{k_2^2 - (m\pi/d_1)^2}}{\epsilon_2^* \sqrt{k_3^2 - (m\pi/d_1)^2}} J_1(\sqrt{k_3^2 - (m\pi/d_1)^2}c)$$

$$= A_{m(2)} [J_1(\sqrt{k_2^2 - (m\pi/d_1)^2}c) + Q_{2m} N_1(\sqrt{k_2^2 - (m\pi/d_1)^2}c)]. \tag{31}$$

We can determine the coefficients  $Q_{2m}$  from eqs (30) and (31)

$$Q_{2m} = \frac{ZJ_0(\sqrt{k_2^2 - (m\pi/d_1)^2}c) - J_1(\sqrt{k_2^2 - (m\pi/d_1)^2}c)}{N_1(\sqrt{k_2^2 - (m\pi/d_1)^2}c) - ZN_0(\sqrt{k_2^2 - (m\pi/d_1)^2}c)},$$
(32)

where

$$Z = \frac{\epsilon_3^* \sqrt{k_2^2 - (m\pi/d_1)^2} J_1(\sqrt{k_3^2 - (m\pi/d_1)^2} c)]}{\epsilon_2^* \sqrt{k_3^2 - (m\pi/d_1)^2} J_0(\sqrt{k_3^2 - (m\pi/d_1)^2} c)}.$$
 (33)

Equations (24) and (27) can be combined to form

$$\vec{A}_2 = \mathbf{L_5} \mathbf{L_6} \vec{A}_2. \tag{34}$$

In order to have a nontrivial solution to this homogeneous system of equations, the determinant of the coefficients

$$\det\left(\mathbf{I} - \mathbf{L_5}\mathbf{L_6}\right) = 0,\tag{35}$$

must vanish. Equation (35) yields  $\epsilon_3^*$ , given complex resonant frequency and quality factor. There are many roots to the equation, but use of an accurate initial guess allows convergence to the correct solution. Alternatively, given  $\epsilon_3^*$ , the complex resonant frequency can be determined.

The matrices  $L_5$  and  $L_6$  have infinite dimension. In calculations, the matrices must be truncated. Numerical calculation shows that in regions 2 and 3, only 2 to 4 eigenfunctions are required

since the fields are strongly evanescent. This can be seen by examination of the argument of the Bessel function in region 3,  $\sqrt{k_3^2 - (m\pi/d_1)^2}$ . Since  $d_1$  is usually only a few millimeters, this quantity has a large imaginary component which produces a strong damping. In region 1, since the dimensions are larger, there is less damping, and more eigenfunctions are required to obtain a converged solution. In region 1, 20 to 90 eigenfunctions are required for accurate calculation of permittivity.

#### 3. Cavity Losses

In this section we summarize the theory for calculation of dielectric losses in the reentrant cavity [4]. Losses in cavities originate from imperfectly conducting walls, sample loss, and coupling port losses. The analysis of cavity loss is more complicated than the analysis of the empty cavity when the cavity is partially filled with material.

In the time domain, the electric fields in a lossy cavity are of the form

$$\vec{E} \approx \exp(j\omega t - \alpha t)\vec{E}_0,$$
 (36)

where  $\alpha$  is an attenuation factor due to dielectric, coupling port, and cavity wall losses.

The stored electric and magnetic energy in a cavity is

$$U_{se} = \frac{1}{4} Re \int \vec{D} \cdot \vec{E} dV, \qquad (37)$$

$$U_{sm} = \frac{1}{4} Re \int \vec{B} \cdot \vec{H} \, dV. \tag{38}$$

Since the stored electric and magnetic energies are equal at resonance,

$$U_{se} = \int \frac{\epsilon_r' \epsilon_0}{4} |\vec{E}|^2 dV = \int \frac{\mu_r' \mu_0}{4} |\vec{H}|^2 dV = U_{sm}.$$
 (39)

Therefore the total stored energy in a cavity is

$$U_s = 2U_{se} = 2U_{sm}. (40)$$

The total stored energy dissipated in a cavity evolves in time as

$$\frac{dU_s}{dt} = -2\alpha U_s,\tag{41}$$

or

$$U_s(t) = U_{s0} \exp\left(-2\alpha t\right). \tag{42}$$

In the forthcoming analysis it is necessary to study both the cases where the cavity is completely filled with material and where the cavity is partially filled. The power dissipated in a material that completely fills a cavity is

$$W_d = \int \frac{\sigma_d}{2} |E|^2 dV + \int \frac{\omega \mu''}{2} |H|^2 dV, \tag{43}$$

where  $\sigma_d$  is the effective conductivity of the dielectric,  $\sigma_d = \omega \epsilon'' + \sigma$ , and  $\sigma$  is defined by  $\vec{J} = \sigma \vec{E}$ .

The quality factor due to a dielectric that completely fills the cavity is used to define the loss tangent of the material under test

$$Q_s = \frac{\omega \text{ (average stored energy)}}{\text{power loss per cycle}} = \frac{\omega U_{sf}}{W_{df}} = \frac{\omega \epsilon_r' \epsilon_0}{\sigma_d} = \frac{1}{\tan \delta},$$
 (44)

where the subscript f refers to filled cavity. Generally, the materials under test will only partially fill the cavity. Since the dielectric does not completely fill the cavity, a correction must be applied. In what follows we outline the procedure for calculating the correction due to partial dielectric filling. The correction is obtained by considering losses in both the air-filled and dielectric-filled sections of the cavity separately.

The power dissipated in walls and end plates is given by integration of the Poynting vector over the surfaces [5]

$$W_w = \frac{R_s}{2} \int |H_\phi|^2 dS,\tag{45}$$

where the surface resistance is  $R_s = \sqrt{\omega \mu'/2\sigma_w} = 1/d\sigma_w$ ,  $\sigma_w$  is the conductivity of the walls, and d is the effective penetration depth into the walls.

The total quality factor in the cavity is the ratio of energy stored in cavity and dielectric to power dissipated in walls, end plates, dielectric, and coupling ports

$$Q_t = \frac{\omega(U_{sd} + U_{sa})}{W_w + W_d + W_{cp}},\tag{46}$$

where  $U_{sd}$  is the energy stored in the dielectric,  $U_{sa}$  is energy stored in air section of the cavity that contains a sample, and  $W_{cp}$  is the loss due to coupling ports. The coupling-port losses can be obtained by circle-fit procedures [6]. The quality factor without sample loss is  $Q'_t$ 

$$Q_t' = \frac{\omega(U_{sd} + U_{sa})}{W_w + W_{cp}}. (47)$$

In the nonmagnetic case, if we write  $W_d = p \tan \delta$ , where p is a parameter identified after performing the integration in eq (43) over the sample volume, then the net loss tangent can be

calculated using eqs (46) and (47) given expressions for  $U_s$ ,  $U_{sa}$ ,  $W_w$ , and  $W_{cp}$  and eq (47). It can be put in the form

 $\tan \delta = \frac{p}{\omega(U_s + U_{sa})} \left( \frac{1}{Q_t} - \frac{1}{Q_t'} \right). \tag{48}$ 

 $Q'_t$  is not directly measurable, however, a theoretical value for  $Q'_t$  can be calculated from eq (47), if the wall penetration depth is known. An estimate of wall penetration depth can be calculated from quality-factor measurement on the empty cavity:

$$Q_e = \frac{\omega U_e}{W_w + W_{cp}} \; ; \tag{49}$$

therefore, the penetration depth is

$$d = \frac{\int_s |H_{\phi}|^2 dS}{2\sigma_w(\frac{\omega U_e}{Q_e} - W_{cp})}.$$
 (50)

The calculated penetration depth can then be used in eq (47) for use in eq (48).

#### 3.1. Wall Losses

Equation (45) yields the wall losses given the surface conductivity. The integrals can be calculated analytically on the outer walls, end plates, and inner conductor. The radial integration is slightly more complicated since the radial functions are not orthogonal.

The total wall loss is

$$P_{w} = \frac{R_{s}}{2} \int |H_{\phi}|^{2} dS$$

$$= \pi R_{s} \left[ \sum_{m=0}^{\infty} B_{mm}^{2} |A_{m(1)} \frac{j\omega\epsilon_{1}^{*}}{\sqrt{k_{1}^{2} - (m\pi/L)^{2}}} \left[ J_{1} (\sqrt{k_{1}^{2} - (m\pi/L)^{2}} b) + Q_{1m} N_{1} (\sqrt{k_{1}^{2} - (m\pi/L)^{2}} b) \right] \right]^{2}$$

$$+ \sum_{m=0}^{\infty} B_{mm}^{2} |A_{m(1)} \frac{j\omega\epsilon_{1}^{*}}{\sqrt{k_{1}^{2} - (m\pi/L)^{2}}} \left[ J_{1} (\sqrt{k_{1}^{2} - (m\pi/L)^{2}} a) + Q_{1m} N_{1} (\sqrt{k_{1}^{2} - (m\pi/L)^{2}} a) \right] \right]^{2}$$

$$- \int_{0}^{d_{1}} |\sum_{m=0}^{\infty} A_{m(1)} \frac{j\omega\epsilon_{1}^{*}}{\sqrt{k_{1}^{2} - (m\pi/L)^{2}}} \left[ J_{1} (\sqrt{k_{1}^{2} - (m\pi/L)^{2}} a) + Q_{1m} N_{1} (\sqrt{k_{1}^{2} - (m\pi/L)^{2}} a) \right]$$

$$\times \cos ((d_{2} - z)m\pi/L) |^{2} dz$$

$$+ 2 \int_{0}^{b} \rho |\sum_{m=0,2,...} A_{m(1)} \frac{j\omega\epsilon_{1}^{*}}{\sqrt{k_{1}^{2} - (m\pi/L)^{2}}} \left[ J_{1} (\sqrt{k_{1}^{2} - (m\pi/L)^{2}} \rho) + Q_{1m} N_{1} (\sqrt{k_{1}^{2} - (m\pi/L)^{2}} \rho) \right] |^{2} d\rho$$

$$+ 2 \int_{c}^{c} \rho |\sum_{m=0,2,...} A_{m(2)} \frac{j\omega\epsilon_{2}^{*}}{\sqrt{k_{2}^{2} - (m\pi/L)^{2}}} \left[ J_{1} (\sqrt{k_{2}^{2} - (m\pi/L)^{2}} \rho) + Q_{2m} N_{1} (\sqrt{k_{2}^{2} - (m\pi/L)^{2}} \rho) \right] |^{2} d\rho$$

$$+ 2 \int_{0}^{c} \rho |\sum_{m=0,2,...} A_{m(3)} \frac{j\omega\epsilon_{2}^{*}}{\sqrt{k_{2}^{2} - (m\pi/L)^{2}}} J_{1} (\sqrt{k_{3}^{2} - (m\pi/L)^{2}} \rho) |^{2} d\rho |.$$
(51)

The loss characteristics of various metals used in cavity construction are given in table 1.

Table 1: Conductivities of metals

Material	Conductivity, $\sigma$	Skin Depth, d (10 GHz)
	$(\times 10^7 \text{ S/m})$	$(\times 10^{-7}) \text{ m}$
Cu	5.80	6.60
Al	3.72	8.26
Ag	6.17	6.42
Au	4.10	7.85
70-30 brass	1.57	12.70

#### 4. Measurements

Permittivity measurements were performed on a number of well-characterized materials. The results are given in table 2. Uncertainties were calculated by comparison with previous measurements of these materials. Numerical experimentation was performed on the convergence of the solution as a function of the number of  $TM_{0m}$  modes used in the expansions. 20 to 90 axial eigenfunctions in region 1 and 2 eigenfunctions in regions 2 and 3 were required for these measurements. Higher permittivity requires more expansion functions in region 3. Uncertainties are produced from a number of sources and will be analyzed in more detail in a future publication. Uncertainties for the measurements were calculated by a sensitivity analysis of sample thickness, resonant frequency, and quality factor. The small air gap between sample and electrodes produces a slightly lower measured permittivity. Corrections for the gap are summarized in [7]. The gap effects on the real part of the permittivity can be mitigated by electroplating sample surfaces with copper by applying conducting pastes, or by using tin foil with petroleum jelly as adhesive [8]. In the measurement of loss factor, gap mitigation methods will produce extraneous loss. Therefore,

Table 2: Dielectric measurements

Material	Frequency	Calculated $(\epsilon'_r, \epsilon''_r)$
Crosslinked polystyrene	915 MHz	$(2.524 \pm 0.020, 0.003 \pm 0.002)$
Polytetrafluoroethylene	$905~\mathrm{MHz}$	$(2.072 \pm 0.020, 0.0025 \pm 0.002)$
1723 Glass	840 MHz	$(6.253 \pm 0.045, 0.0217 \pm 0.003)$

the loss measurement should be performed before the permittivity measurement.

#### 5. Conclusions

The goal of this report was the development of the theory for the mode-matching solution for resonance in a reentrant cavity and the presentation of numerical results. The mode matching results in a determinantal equation. The roots of this equation yield the permittivity of the sample. A full-mode model for the cavity was developed and solved numerically. The solution allows accurate measurement of permittivity. Analytical expressions for wall losses were presented. The theoretical approach to characterization of the reentrant cavity was presented.

#### 6. Acknowledgments

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